

PC4H520NIP0F

Mini-flat Half-pitch Package Darlington Phototransistor Output High Collector-emitter Voltage Photocoupler



■ Description

PC4H520NIP0F contains a IRED optically coupled to a phototransistor.

It is packaged in a 4-pin Mini-flat, Half pitch type. Input-output isolation voltage(rms) is 2.5kV. Collector-emitter voltage is 350V and CTR is MIN. 1000% at input current of 1mA.

■ Features

- 1. 4-pin Mini-flat Half pitch package (Lead pitch : 1.27mm)
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. High collector-emitter voltage (V_{CEO}: 350V)
- 4. Darlington phototransistor output (CTR : MIN.1000% at $I_F=ImA,V_{CE}=2V$)
- 5. Isolation voltage between input and output ($V_{iso(rms)}$: 2.5kV)
- 6. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

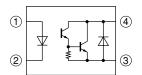
- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC4H52**)
- 2. Package resin : UL flammability grade (94V-0)

■ Applications

1. Modems



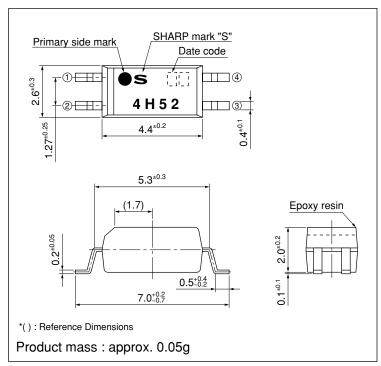
■ Internal Connection Diagram



- ① Anode
- ③ Cathode
- 4 Emitter
- ⑤ Collector

■ Outline Dimensions

(Unit: mm)



Plating material: SnCu (Cu: TYP. 2%)



Date code (2 digit)

	1st o	digit		2nd digit		
Year of production				Month of production		
A.D.	Mark	A.D	Mark	Month	Mark	
1990	A	2002	P	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	T	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	X	August	8	
1998	K	2010	A	September	9	
1999	L	2011	В	October	0	
2000	M	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Country of origin Japan

Rank mark

There is no rank mark indicator.



■ Absolute Maximum Ratings

■ Absolute Maximum Ratings (T _a =25°C)						
	Parameter	Symbol	Rating	Unit		
Input	Forward current	I_F	50	mA		
	*2 Peak forward current	I_{FM}	1	A		
Inj	Reverse voltage	V_R	6	V		
	*1 Power dissipation	P	70	mW		
	Collector-emitter voltage	V_{CEO}	350	V		
Output	Emitter-collector voltage	V _{ECO}	0.1	V		
	Collector current	I_C	120	mA		
	*1 Collector power dissipation	P_{C}	180	mW		
*17	Γotal power dissipation	P _{tot}	210	mW		
Operating temperature		T_{opr}	-40 to +100	°C		
Storage temperature		T_{stg}	-55 to +125	°C		
*3 Isolation voltage		$V_{iso\ (rms)}$	2.5	kV		
*4 Soldering temperature		T_{sol}	260	°C		

^{*1} Mounted glass epoxy PCB (Size : 20mm×20mm×1.6mm)
*2 Pulse width≤100μs, Duty ratio : 0.001
*3 40 to 60%RH, AC for 1 minute, f=60Hz
*4 For 10s

■ Electro-optical Characteristics

 $(T_3=25^{\circ}C)$

								(1_a-25)
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
'	Forward voltage		V_F	$I_F=10mA$	_	1.2	1.4	V
Input	Reverse current		I_R	$V_R=4V$	_	_	10	μΑ
	Terminal capacitance		C_t	V=0, f=1kHz	_	30	250	pF
Output	Collector dark current		I_{CEO}	$V_{CE}=200V, I_{F}=0$	-	-	200	μΑ
	Collector-emitter breakdown voltage		BV _{CEO}	$I_{C}=0.1 \text{ mA}, I_{F}=0$	350	-	-	V
	Current transfer ratio		I_{C}	$I_F=1mA$, $V_{CE}=2V$	10	40	120	mA
	Collector-emitter saturation voltage		V _{CE (sat)}	$I_F=20mA, I_C=100mA$	_	-	1.4	V
Transfer characteristics	Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω
	Floating capacitance		C_{f}	V=0, f=1MHz	_	0.6	1.0	pF
	Cut-off frequency		f_C	V_{CE} =2V, I_{C} =20mA, R_{L} =100 Ω -3dB	1	7	_	kHz
	Response time	Rise time	t _r	V_{CE} =2V, I_C =20mA, R_L =100 Ω	_	100	300	μs
		Fall time	t_{f}		_	20	100	μs



Fig.1 Forward Current vs. Ambient Temperature

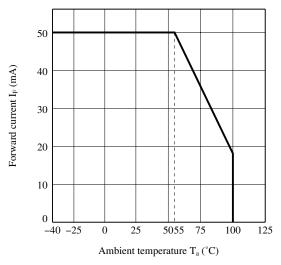


Fig.3 Collector Power Dissipation vs. Ambient Temperature

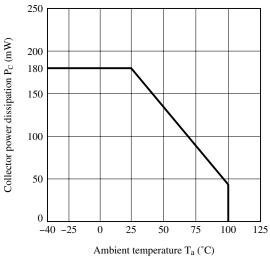


Fig.5 Peak Forward Current vs. Duty Ratio

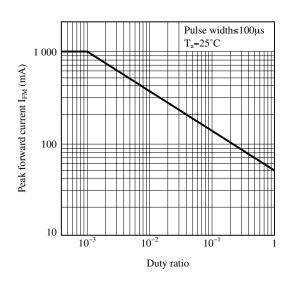


Fig.2 Diode Power Dissipation vs. Ambient Temperature

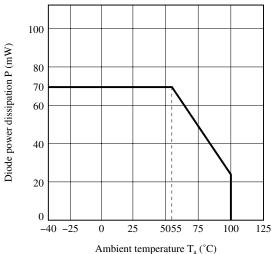


Fig.4 Total Power Dissipation vs. Ambient Temperature

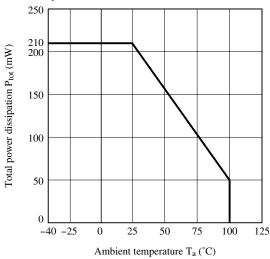


Fig.6 Forward Current vs. Forward Voltage

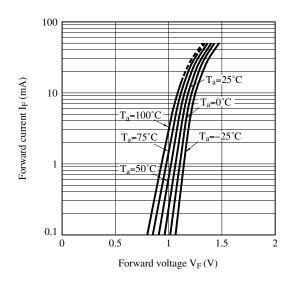




Fig.7 Current Transfer Ratio vs. Forward Current

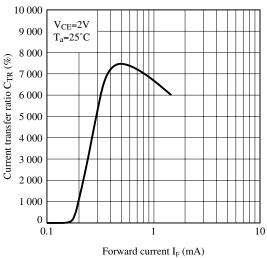


Fig.9 Collector Current vs. Forward Current

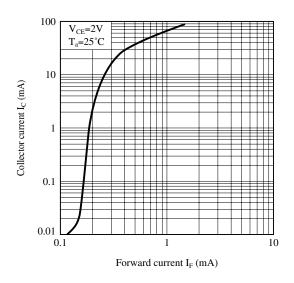


Fig.11 Collector Dark Current vs. Ambient Temperature

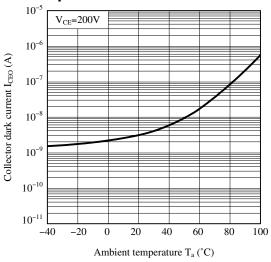


Fig.8 Collector Current vs. Collector-emitter Voltage

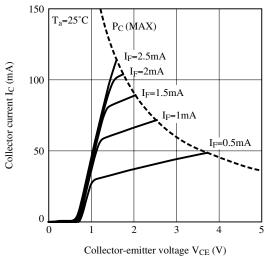


Fig.10 Relative Current Transfer Ratio vs.
Ambient Temperature

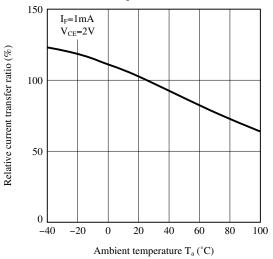
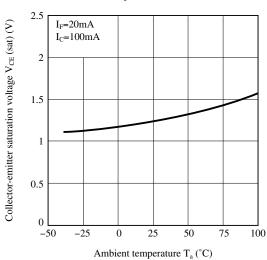


Fig.12 Collector Sayuration Voltage vs.
Ambient Temperature

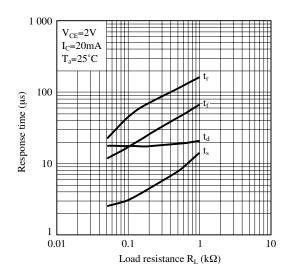


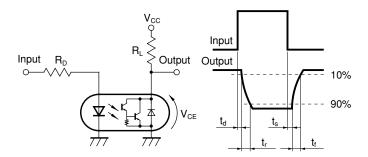
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Fig.13 Response Time vs. Load Resistance

Fig.14 Test Circuit for Response Time





Please refer to the conditions in Fig.13

Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

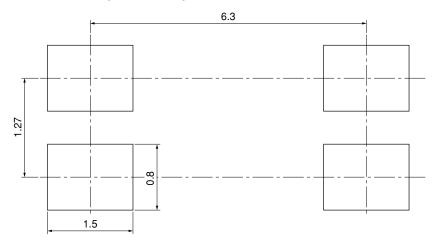
This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended Foot Print (reference)



(Unit: mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

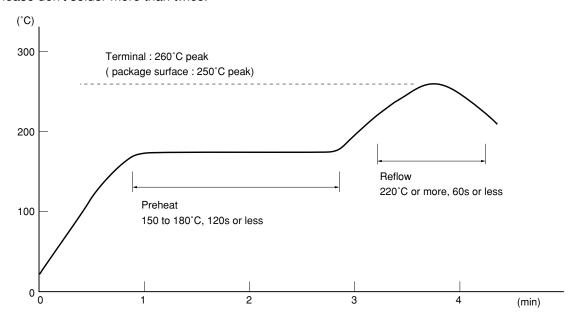
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 260°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

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■ Package specification

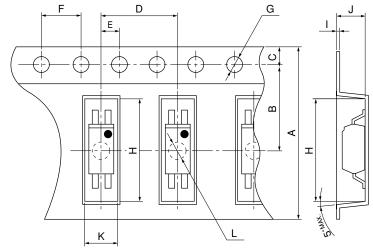
● Tape and Reel package

Package materials Carrier tape : PS

Cover tape: PET (three layer system)

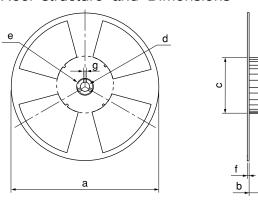
Reel: PS

Carrier tape structure and Dimensions



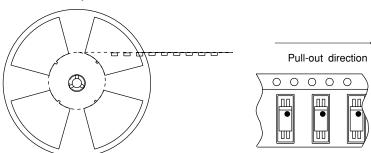
Dimensions List (Unit: mm) C Е F D G A 12.0±0.3 $5.5^{\pm0.1}$ $1.75^{\pm0.1}$ $8.0^{\pm0.1}$ $2.0^{\pm0.1}$ $4.0^{\pm0.1}$ $\phi 1.5^{+0.1}_{-0}$ Н K L Ι J $7.5^{\pm0.1}$ $0.3^{\pm0.05}$ 2.3^{±0.1} 3.1^{±0.1} φ1.6^{+0.1}

Reel structure and Dimensions



Dimensior	ns List	(Unit: mm)		
a	a b		d	
330	13.5 ^{±1.5}	100±1.0	13 ^{±0.5}	
e	f	g		
23 ^{±1.0}	2.0 ^{±0.5}	2.0 ^{±0.5}		

Direction of product insertion



[Packing: 3 000pcs/reel]



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- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
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